



IFW

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

**PATENT**

Applicant: Kuo-Chuan LIU, et al.

Serial No.: 10/807,605

Filed: March 23, 2004

For: *Methods of Forming LaNiO<sub>3</sub>  
Conductive Layers, Ferro-  
Electric Devices with LaNiO<sub>3</sub>  
Layers, and Precursor Formation  
Solutions*

Art Unit: 1775

Examiner: LAM, Cathy

Atty. Dkt.: 02EK-105600

**CERTIFICATE OF  
MAILING/TRANSMISSION  
(37 C.F.R. § 1.8(a))**

I hereby certify that this correspondence is, on  
the date shown below, being:

(X) deposited with the United States Postal  
Service with sufficient postage as first-class  
mail in an envelope addressed to:

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

( ) transmitted by facsimile to the Patent and  
Trademark Office

5/24/05   
Date Jordan Wilson

**RESPONSE TO RESTRICTION REQUIREMENT**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450


Sir:

In response to the Restriction Requirement mailed by the U.S. Patent and Trademark Office  
on April 26, 2005, Applicant elects Group I, claims 1 – 24 without traverse.

May 24, 2005

Sheppard Mullin Richter & Hampton LLP  
4 Embarcadero Center, 17<sup>th</sup> Floor  
San Francisco, CA 94111-4106  
Tel: (415) 434-9100  
Fax: (415) 434-3947

Respectfully submitted,

  
David Schnapf  
Registration No. 31,566